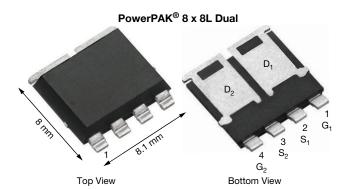
SQJQ910EL

ISHA www.vishay.com

Vishay Siliconix

Automotive Dual N-Channel 100 V (D-S) 175 °C MOSFET



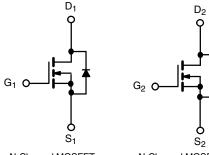
PRODUCT SUMMARY	
V _{DS} (V)	100
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0086
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.0114
I _D (A) per leg	70
Configuration	Dual
Package	PowerPAK 8 x 8L

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Fully lead (Pb)-free device
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN FREE



N-Channel MOSFET



ABSOLUTE MAXIMUM RATIN	GS (T _C = 25 °C, unless	otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	100	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C ª		70		
Continuous drain current	T _C = 125 °C	I _D	40		
Continuous source current (diode conduction) ^a		I _S	100	А	
Pulsed drain current ^b		I _{DM}	280		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	42		
Single pulse avalanche energy		E _{AS}	88	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	187	W	
Maximum power dissipation 5	T _C = 125 °C	P _D	62	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temper	rature) ^{d, e}		260	-C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	85	°C/W
Junction-to-case (drain)		R _{thJC}	2	C/W

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (www.vishay.com/doc?73257). The PowerPAK 8 x 8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	100	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	1.5	2	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	$0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	40	-	-	А
		V _{GS} = 10 V	I _D = 10 A	-	0.0072	0.0086	
		$V_{GS} = 4.5 V$	I _D = 10 A	-	0.0095	0.0114	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 5 A, T _J = 125 °C	-	-	0.0110	Ω
		V _{GS} = 10 V	I _D = 5 A, T _J = 175 °C	-	-	0.0187	
Forward Transconductance ^b	g fs	V _{DS} = 15 V, I _D = 10 A		-	52	-	S
Dynamic ^b		<u>.</u>					
Input capacitance	C _{iss}			-	2266	2832	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 50 V, f = 1 MHz	-	799	1000	pF
Reverse transfer capacitance	C _{rss}			-	34	43	
Total gate charge ^c	Qg			-	46	58	
Gate-source charge c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, I_D = 10 \text{ A}$	-	7	-	nC
Gate-drain charge ^c	Q _{gd}			-	10	-	
Gate resistance	Rg		f = 1 MHz	1.1	1.9	3.0	Ω
Turn-on delay time ^c	t _{d(on)}			-	11	14	
Rise time ^c	t _r	V _{DD}	= 40 V, R_{L} = 4 Ω	-	4	5	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 10 \text{ A},$	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	33	42	ns
Fall time ^c	t _f			-	7	8	
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	280	Α
	V _{SD}	1	= 40 A, V _{GS} = 0	-	1	1.2	V

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$

b. Guaranteed by design, not subject to production testing

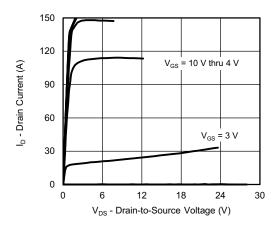
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

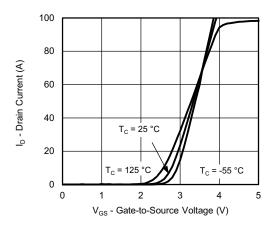
2



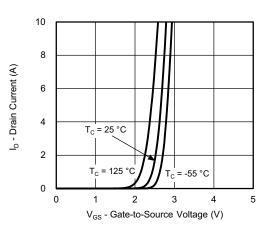
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



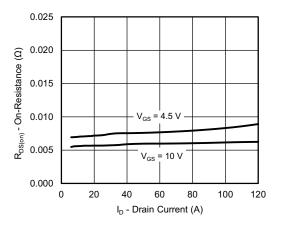
Output Characteristics



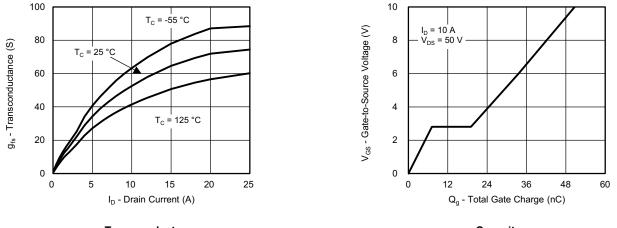
Transfer Characteristics



Transfer Characteristics



On-Resistance vs. Drain Current



Transconductance

Capacitance

S17-0464-Rev. A, 03-Apr-17

3 stions, contact; automostechsupp Document Number: 76026

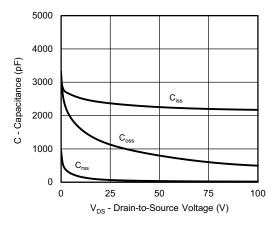
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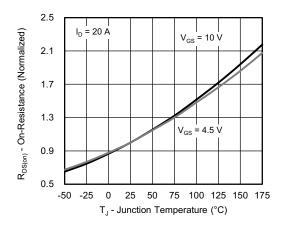
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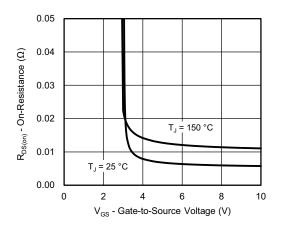
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



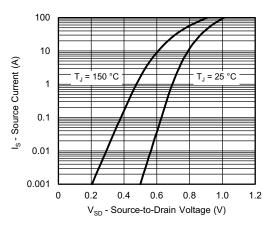
Capacitance



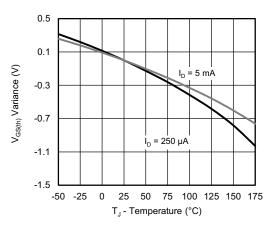
On-Resistance vs. Junction Temperature



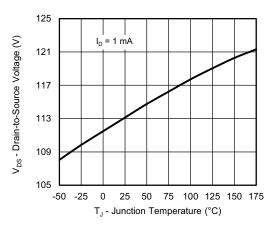
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature

S17-0464-Rev. A, 03-Apr-17

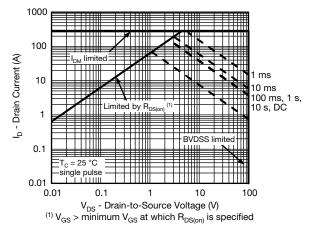
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Document Number: 76026

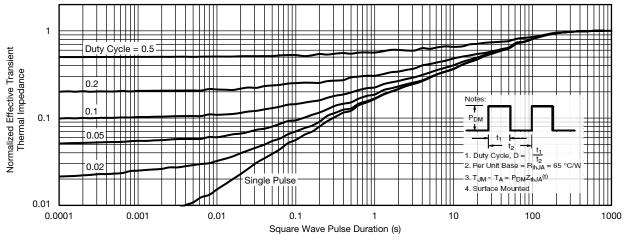
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

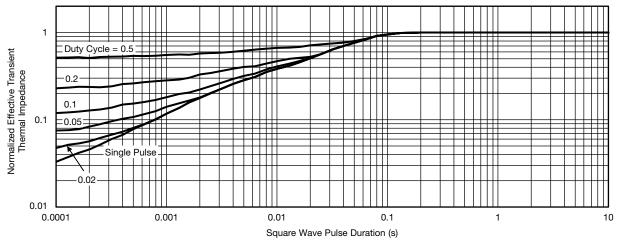


Normalized Thermal Transient Impedance, Junction-to-Ambient



Document Number: 76026

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

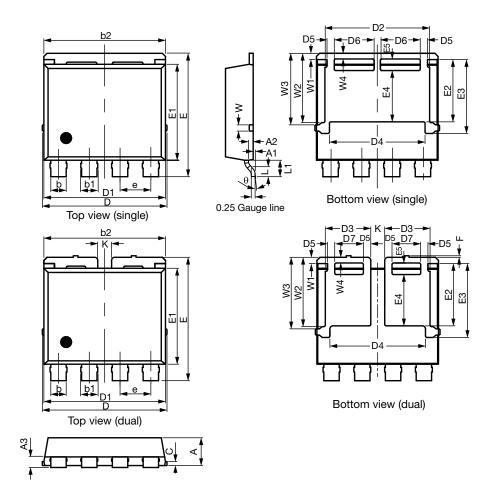
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.70	1.80	1.90	0.067	0.071	0.075	
A1	0.00	0.08	0.13	0.000	0.003	0.005	
A2	0.25	0.30	0.35	0.010	0.012	0.014	
A3	0.55	0.62	0.70	0.022	0.024	0.028	
b	0.92	1.00	1.08	0.036	0.039	0.043	
b1	1.02	1.10	1.18	0.040	0.043	0.046	
b2	7.80	7.90	8.00	0.307	0.311	0.315	
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	8.00	8.10	8.25	0.315	0.319	0.325	
D1	7.80	7.90	8.00	0.307	0.311	0.315	
D2	6.70	6.80	6.90	0.264	0.268	0.272	
D3	2.85	2.95	3.05	0.112	0.116	0.120	
D4	6.11	6.21	6.31	0.241	0.244	0.248	
D5	0.37	0.47	0.57	0.015	0.019	0.022	
D6	2.49	2.59	2.69	0.098	0.102	0.106	
D7	1.76	1.86	1.96	0.069	0.073	0.077	

Revision: 16-Oct-17

Document Number: 67734

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Package Information



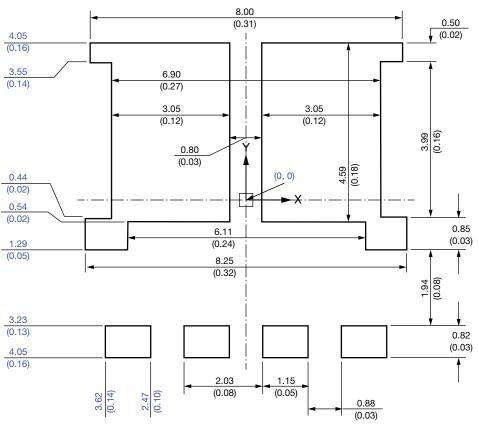


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DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
е	1.95	2.00	2.05	0.077	0.079	0.081	
Е	7.90	8.00	8.10	0.311	0.315	0.319	
E1	6.12	6.22	6.32	0.241	0.245	0.249	
E2	3.94	4.04	4.14	0.140	0.159	0.163	
E3	4.69	4.79	4.89	0.185	0.189	0.193	
E4	3.23	3.33	3.43	0.127	0.131	0.135	
E5	0.65	0.75	0.85	0.026	0.030	0.033	
F	0.00	0.10	0.15	0.000	0.004	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К	0.80	0.90	1.00	0.031	0.035	0.039	
W	0.30	0.40	0.50	0.012	0.016	0.020	
W1	0.30	0.40	0.50	0.012	0.016	0.020	
W2	4.39	4.49	4.59	0.173	0.177	0.181	
W3	4.54	4.64	4.74	0.179	0.183	0.187	
W4	0.32	0.37	0.42	0.013	0.015	0.017	
θ	6°	10°	14°	6°	10°	14°	



Recommended Minimum PADs for PowerPAK® 8 x 8L Dual



Dimensions in millimeters (inches)

Note

• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



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